Lithography

Lithography: process used to transfer patterns to each layer of the IC

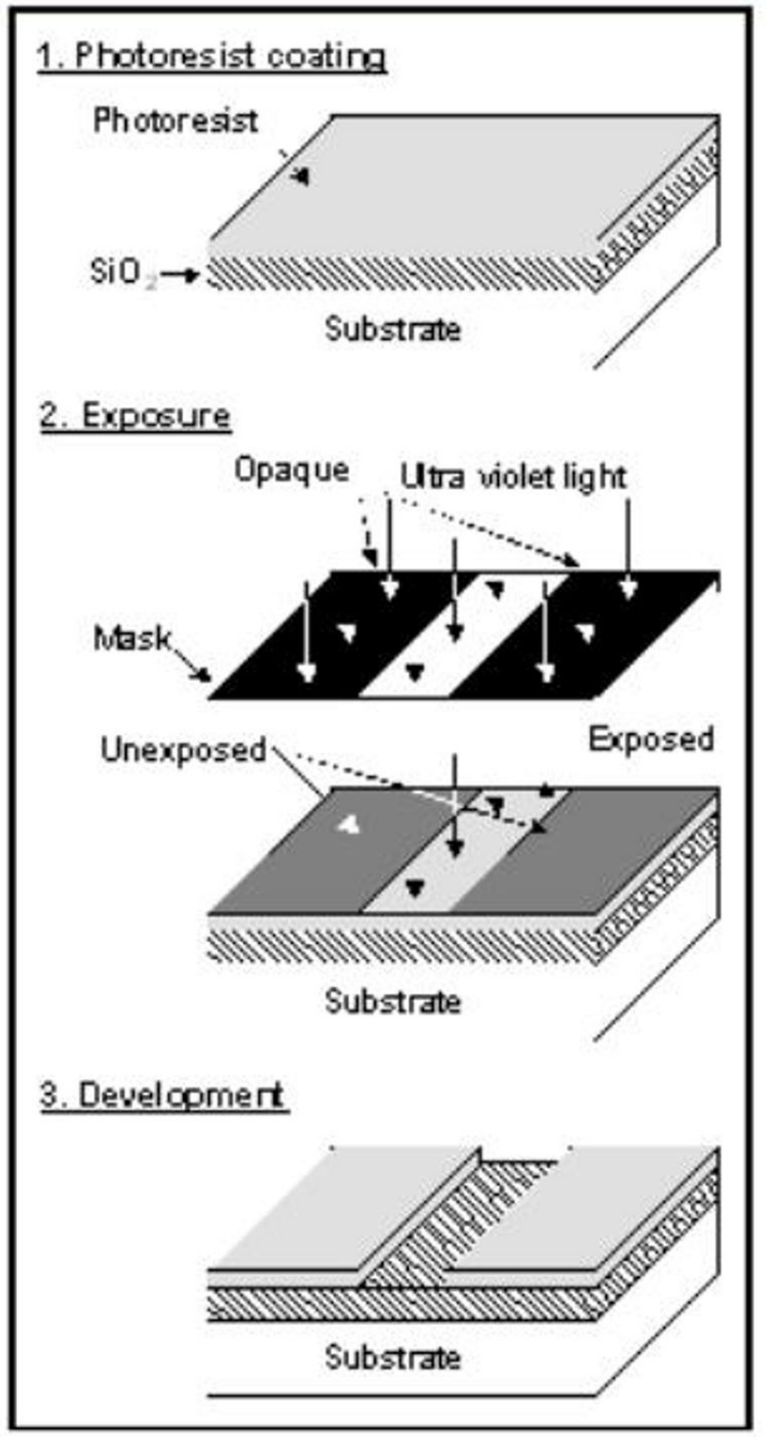
Lithography sequence steps:

- Designer:
  - Drawing the "layer" patterns on a layout editor
- Silicon Foundry:
  - Masks generation from the layer patterns in the design data base
  - Printing: transfer the mask pattern to the wafer surface
  - Process the wafer to physically pattern each layer of the IC

Lithography

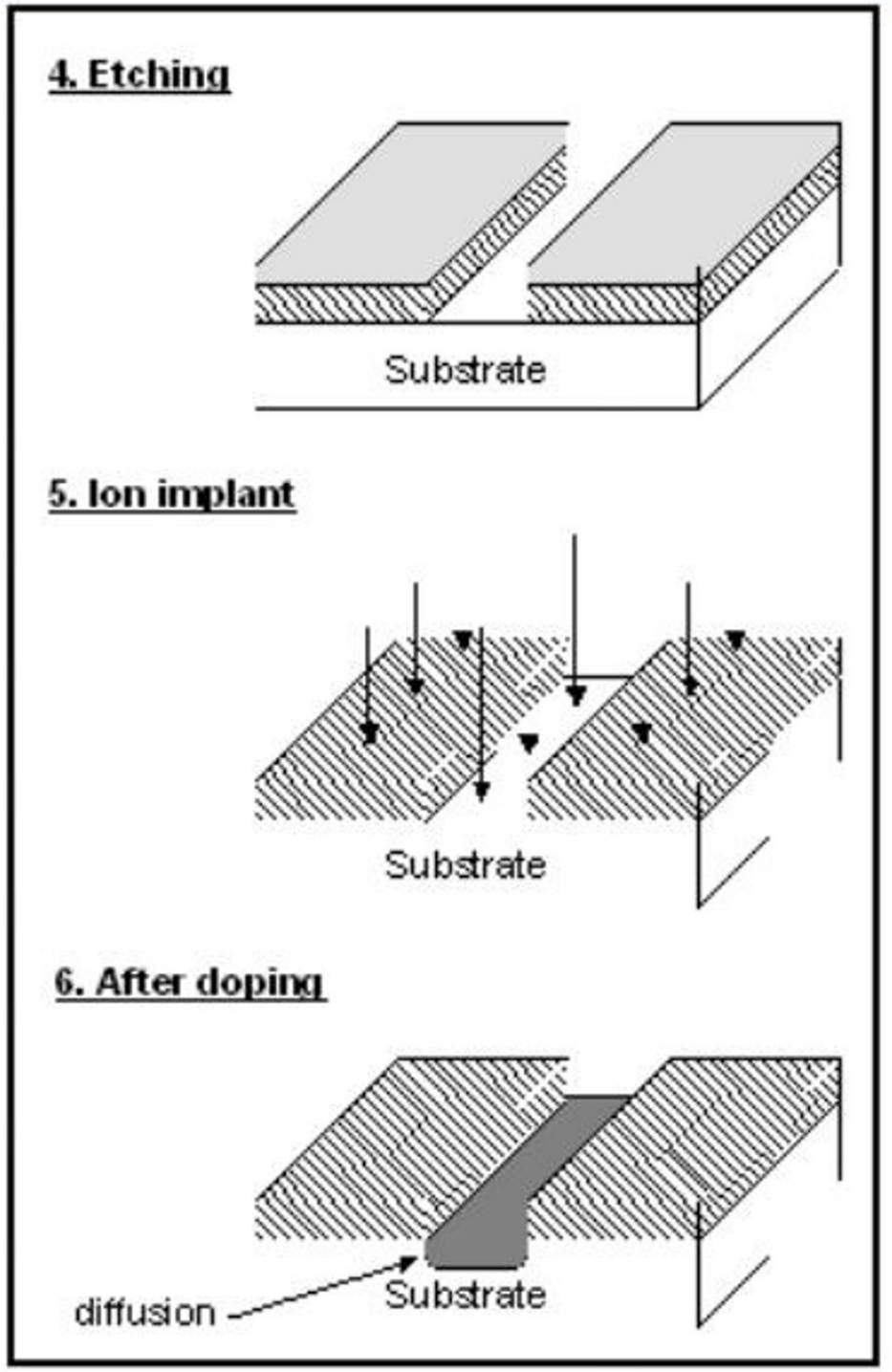
Basic sequence

- The surface to be patterned is:
  - spin-coated with photoresist
  - the photoresist is dehydrated in an oven (photo resist: light-sensitive organic polymer)
- The photoresist is exposed to ultra violet light:
  - For a positive photoresist exposed areas become soluble and non exposed areas remain hard
- The soluble photoresist is chemically removed (development).
  - The patterned photoresist will now serve as an etching mask for the SiO_2



Lithography

- The $SiO_2$is etched away leaving the substrate exposed:
  - the patterned resist is used as the etching mask
- Ion Implantation:
  - the substrate is subjected to highly energized donor or acceptor atoms
  - The atoms impinge on the surface and travel below it
  - The patterned silicon SiO_2serves as an implantation mask
- The doping is further driven into the bulk by a thermal cycle



Lithography

- The lithographic sequence is repeated for each physical layer used to construct the IC. The sequence is always the same:
  - Photoresist application
  - Printing (exposure)
  - Development
  - Etching

Lithography

Patterning a layer above the silicon surface